N-Channel 150 V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
150	0.100 at V_{GS} = 10 V	20
	0.138 at V_{GS} = 4.5 V	16

FEATURES

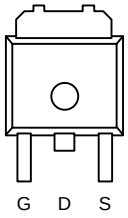
- DT-Trench Power MOSFET
- 100 % Rgand UIS Tested
- 175 °C Junction Temperature

RoHS COMPLIANT

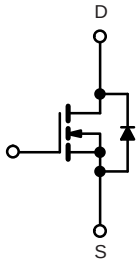
APPLICATIONS

- Primary Side Switch
- DC/DC Converters
- DC/AC Inverters
- Motor Drives

TO-252



Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)				
Parameter		**Symbol**	**Limit**	**Unit**
Drain-Source Voltage		V_{DS}	150	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (T_J = 175 °C)[b]	T_C = 25 °C	I_D	20	A
	T_C = 125 °C		13	
Pulsed Drain Current		I_{DM}	80	
Continuous Source Current (Diode Conduction)		I_S	20	
Avalanche Current		I_{AS}	29	
Repetitive Avalanche Energy (Duty Cycle ≤ 1 %)	L = 0.1 mH	E_{AS}	13.3	mJ
Maximum Power Dissipation[a]	T_C = 25 °C	P_D	67[b]	W
	T_A = 25 °C[c]		3.6	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 175	°C

THERMAL RESISTANCE RATINGS				
Parameter	**Symbol**	**Typical**	**Maximum**	**Unit**
Junction-to-Ambient[c]	R_{thJA}	45	65	°C/W
Junction-to-Case	R_{thJC}	2	2.4	

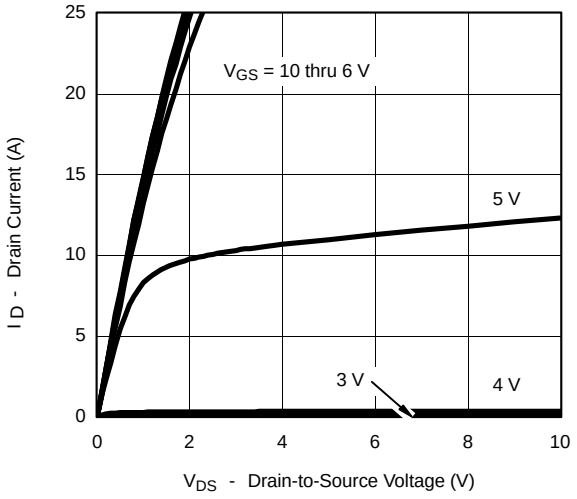
Notes:
a. Duty cycle ≤ 1 %.
b. See SOA curve for voltage derating.
c. When mounted on 1" square PCB (FR-4 material).

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
Parameter	**Symbol**	**Test Conditions**	**Min.**	**Typ.[a]**	**Max.**	**Unit**
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	150			V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	2		4	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 120 V, V_{GS} = 0 V			1	µA
		V_{DS} = 120 V, V_{GS} = 0 V, T_J = 125 °C			50	
		V_{DS} = 120 V, V_{GS} = 0 V, T_J = 175 °C			250	
On-State Drain Current[b]	$I_{D(on)}$	V_{DS} = 5 V, V_{GS} = 10 V	20			A
Drain-Source On-State Resistance[b]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 10 A		0.100	0.122	Ω
		V_{GS} = 10 V, I_D = 10 A, T_J = 125 °C		0.128	0.175	
		V_{GS} = 10 V, I_D = 10 A, T_J = 175 °C		0.159	0.193	
		V_{GS} = 4.5 V, I_D = 10 A		0.138	0.166	
Forward Transconductance[b]	g_{fs}	V_{DS} = 15 V, I_D = 10 A		25		S
Dynamic[a]						
Input Capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 120 V, f = 1 MHz		1850		pF
Output Capacitance	C_{oss}			615		
Reverse Transfer Capacitance	C_{rss}			70		
Total Gate Charge[c]	Q_g	V_{DS} = 120 V, V_{GS} = 10 V, I_D = 10 A		20	25	nC
Gate-Source Charge[c]	Q_{gs}			5.5		
Gate-Drain Charge[c]	Q_{gd}			7		
Gate Resistance	R_g		1		3.2	Ω
Turn-On Delay Time[c]	$t_{d(on)}$	V_{DD} = 120 V, R_L = 5 Ω I_D ≅ 10 A, V_{GEN} = 10 V, R_G = 2.5Ω		8	12	ns
Rise Time[c]	t_r			35	55	
Turn-Off Delay Time[c]	$t_{d(off)}$			17	25	
Fall Time[c]	t_f			30	45	
Source-Drain Diode Ratings and Characteristic (T_C = 25 °C)						
Pulsed Current	I_{SM}				80	A
Diode Forward Voltage[b]	V_{SD}	I_F = 10 A, V_{GS} = 0 V		0.7	1.2	V
Source-Drain Reverse Recovery Time	t_{rr}	I_F = 10 A, dI/dt = 100 A/µs		55	85	ns

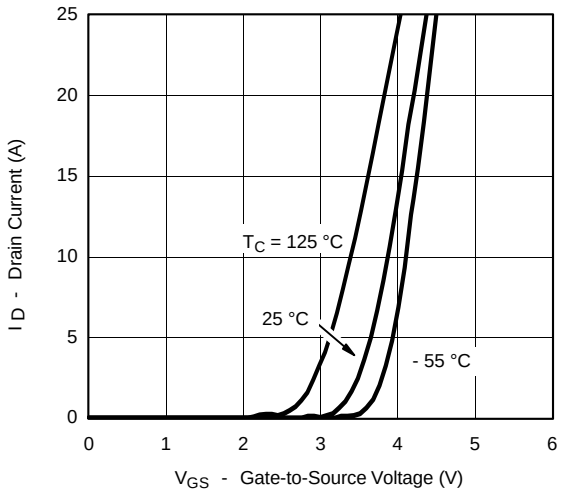
Notes:
a. Guaranteed by design, not subject to production testing.
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

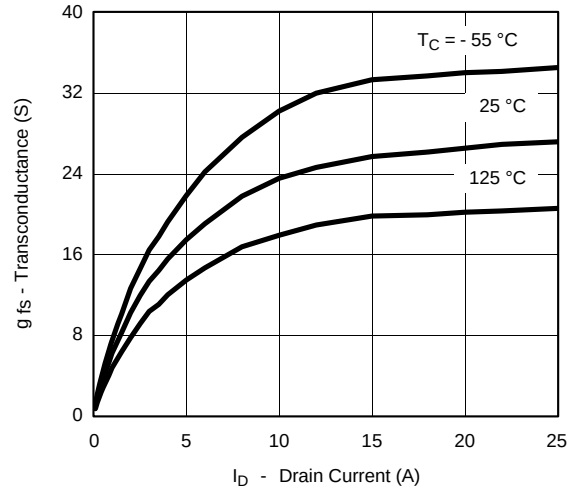
TYPICAL CHARACTERISTICS (25 °C unless noted)



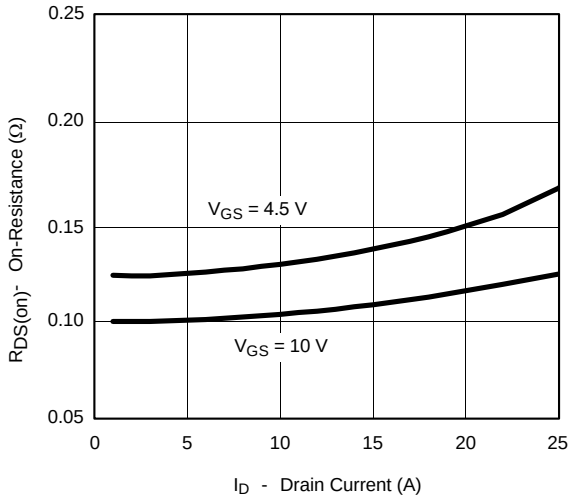
Output Characteristics



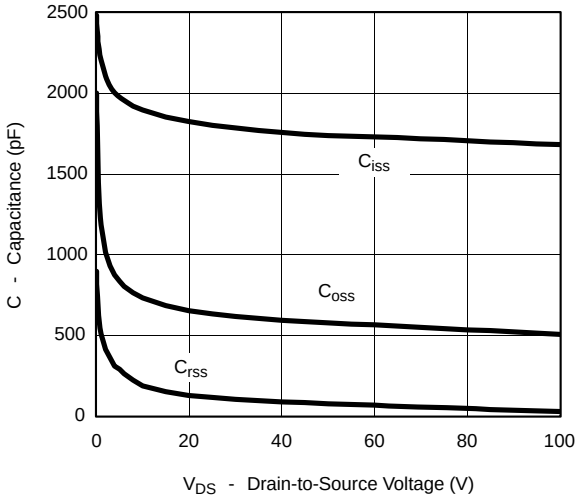
Transfer Characteristics



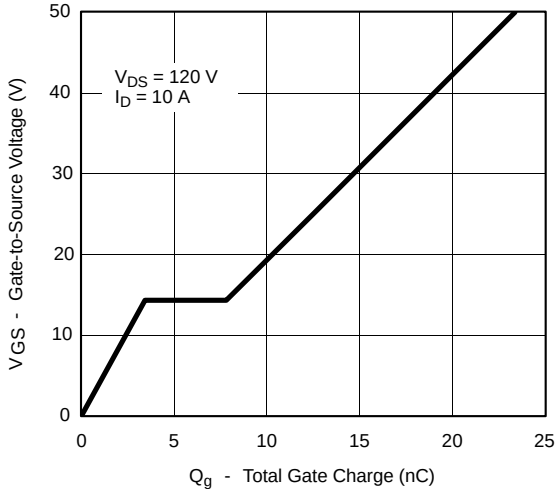
Transconductance



On-Resistance vs. Drain Current

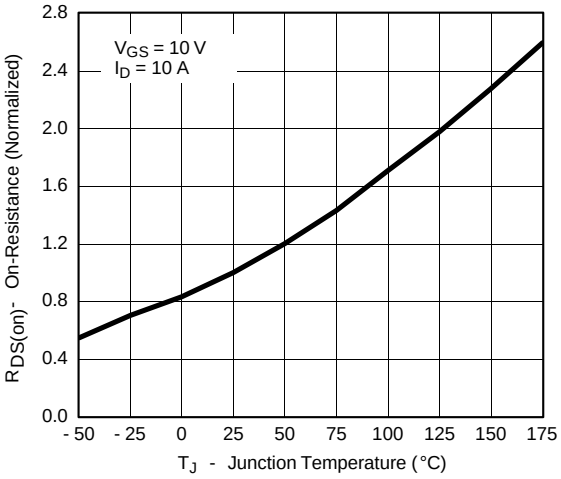


Capacitance

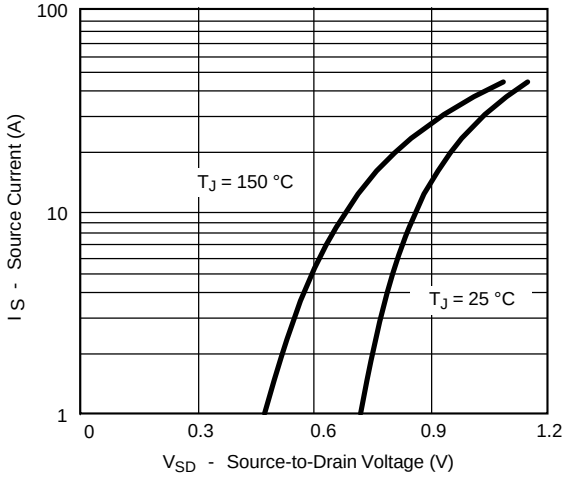


Gate Charge

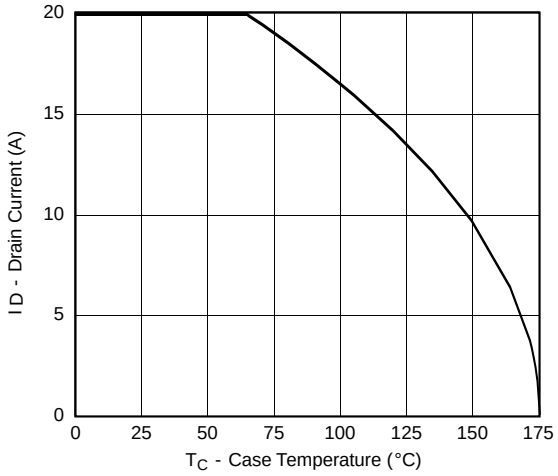
TYPICAL CHARACTERISTICS (25 °C unless noted)



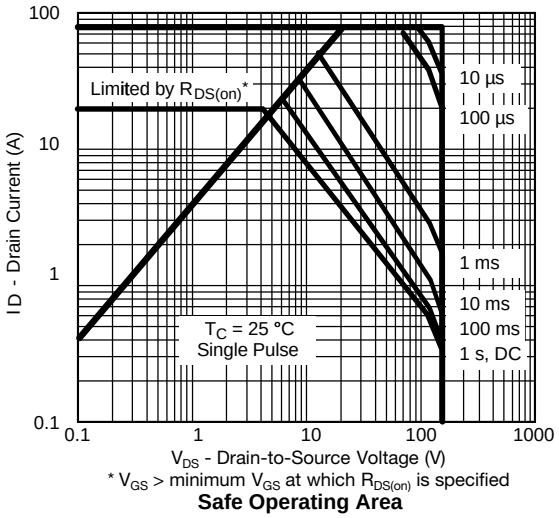
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



Maximum Avalanche Drain Current vs. Case Temperature



Safe Operating Area

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